

40V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

PowerDI3333-8

Product Summary

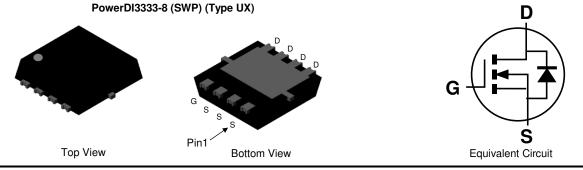
BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C	
40V	7.4mΩ @ V _{GS} = 10V	67.2A	

Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- Excellent Q_{GD} × R_{DS(ON)} Product (FOM)
- Low R_{DS(ON)} Ensures On-State Losses are Minimized
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Wettable Flank for Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Package: PowerDI[®]3333-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.072 grams (Approximate)



Ordering Information (Note 4)

Part Number	Paakaga	Packing		
Part Number	Package	Qty.	Carrier	
DMTH46M7SFVW-7	PowerDI3333-8 (SWP) (Type UX)	2,000	Tape & Reel	
DMTH46M7SFVW-13	PowerDI3333-8 (SWP) (Type UX)	3,000	Tape & Reel	

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



 $\frac{M7S}{YY} = Product Type Marking Code$ $\frac{YY}{YY} WW = Date Code Marking$ $\frac{YY}{Y} = Last Two Digits of Year (ex: 22 = 2022)$ WW = Week Code (01 to 53)

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Motor controls
- Power management functions
- DC-DC converters



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	40	V	
Gate-Source Voltage		V _{GSS}	±20	V
	Tc = +25°C	1-	67.2	A
Continuous Drain Current (Note 6), V _{GS} = 10V	$T_{C} = +100^{\circ}C$	ID	47.5	
	T _A = +25°C		16.3	A
Continuous Drain Current (Note 5), VGS = 10V	T _A = +100°C	lo	11.5	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	•	ldм	260	А
Maximum Continuous Body Diode Forward Current (Note 6)		ls	65	А
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle	lsм	260	А	
Avalanche Current, L = 0.1mH	las	26.6	А	
Avalanche Energy, L = 0.1mH	Eas	35.3	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	TA = +25°C	PD	3.2	W
Thermal Resistance, Junction to Ambient (Note 5)		RθJA	46.8	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	54.5	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	2.75	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	Cymbol		. 76	max	0		
Drain-Source Breakdown Voltage	BV _{DSS}	40			V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	_		1	μA	V _{DS} = 32V, V _{GS} = 0V	
Gate-Source Leakage	lgss	_		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	2		4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)		5.7	7.4	mΩ	$V_{GS} = 10V, I_{D} = 20A$	
Diode Forward Voltage	Vsd	_	0.9	1.2	V	$V_{GS} = 0V$, $I_S = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		1315	—			
Output Capacitance	Coss		517		pF		
Reverse Transfer Capacitance	Crss	_	30.9	_			
Gate Resistance	Rg	-	1.13		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	-	14.8			V _{DS} = 20V, I _D = 20A, V _{GS} = 10V	
Gate-Source Charge	Qgs	-	1.9		nC		
Gate-Drain Charge	Qgd	-	5.2				
Turn-On Delay Time	tD(ON)	_	8.67	_		$\label{eq:VDD} \begin{array}{l} V_{DD} = 20V, V_{GS} = 10V, \\ R_g = 3\Omega, I_D = 20A \end{array}$	
Turn-On Rise Time	tR		16.1	—			
Turn-Off Delay Time	tD(OFF)	_	15.9	_	ns		
Turn-Off Fall Time	tF		9.07	—			
Body Diode Reverse Recovery Time	trr		105	—	ns	1- 20A di/dt 200A/uc	
Body Diode Reverse Recovery Charge	Q _{RR}	_	229	—	nC	I _F = 20A, di/dt = 300A/μs	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1 inch square copper plate.

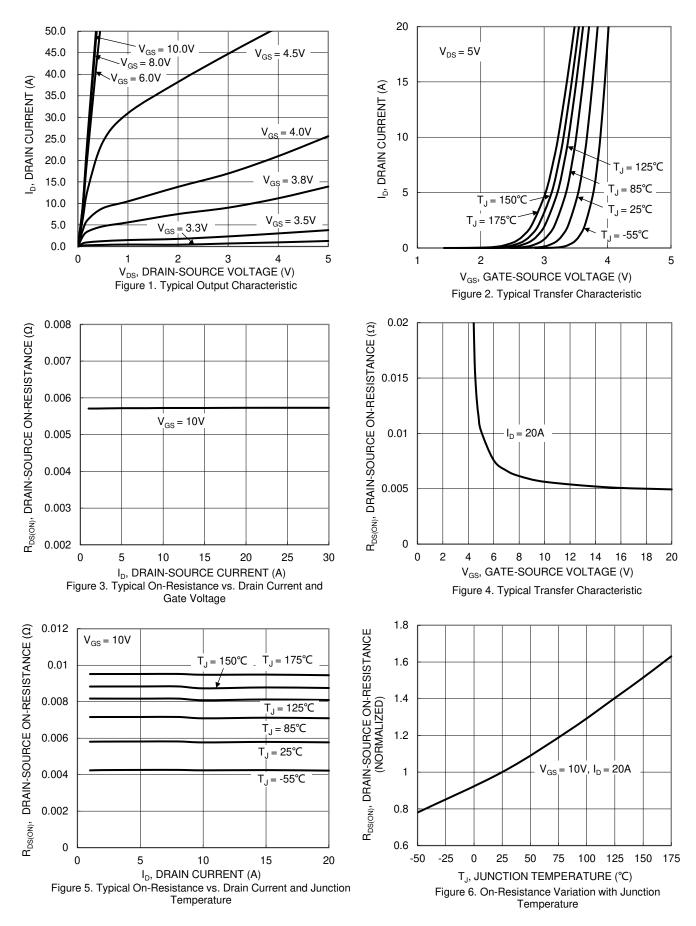
6. Thermal resistance from junction to soldering point (on the exposed drain pad).

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to production testing.

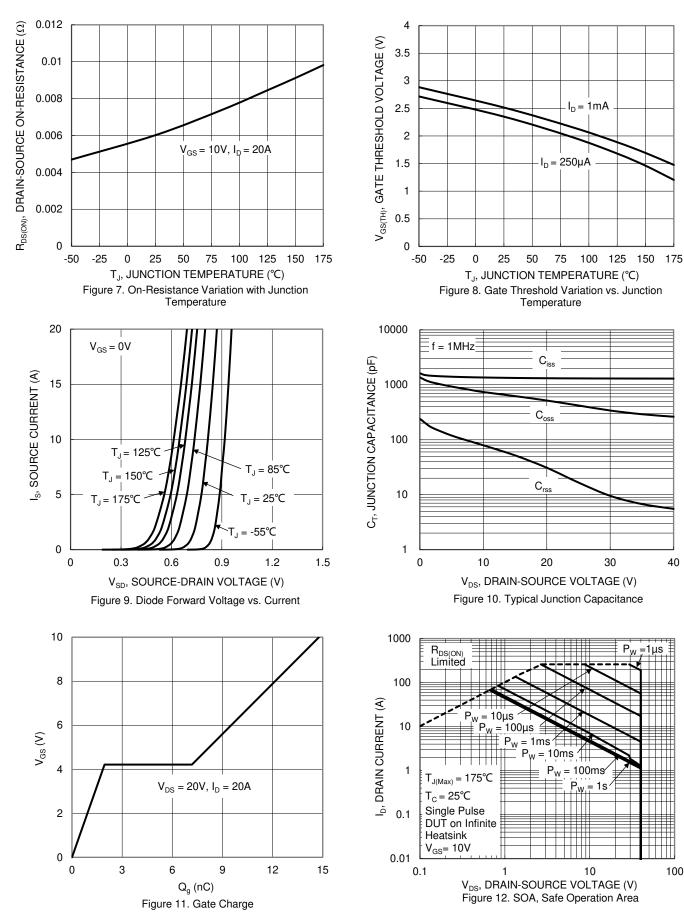


DMTH46M7SFVW



DMTH46M7SFVW Document number: DS42502 Rev. 4 - 2

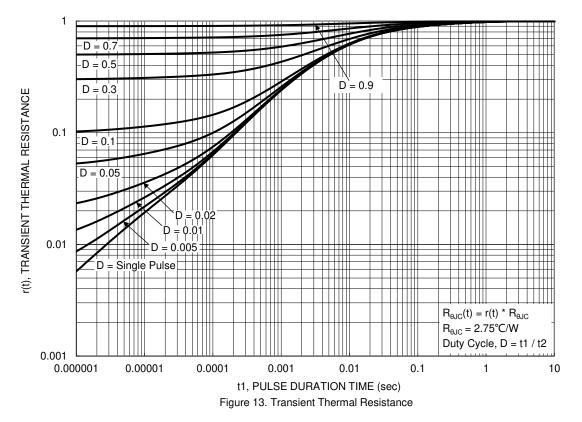




40

100

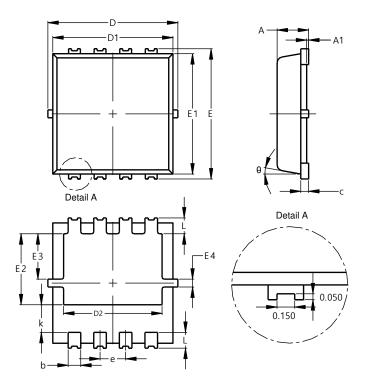






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



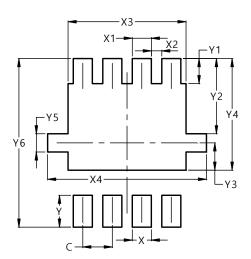
PowerDI3333-8	(SWP)	(Type UX)
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PowerDI3333-8 (SWP)						
	(Type UX) ´					
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
Ε	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E3	0.95	1.35	1.15			
E4	0.10	0.30	0.20			
е	_	_	0.65			
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
X3	2.600
X4	3.500
Y	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700



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